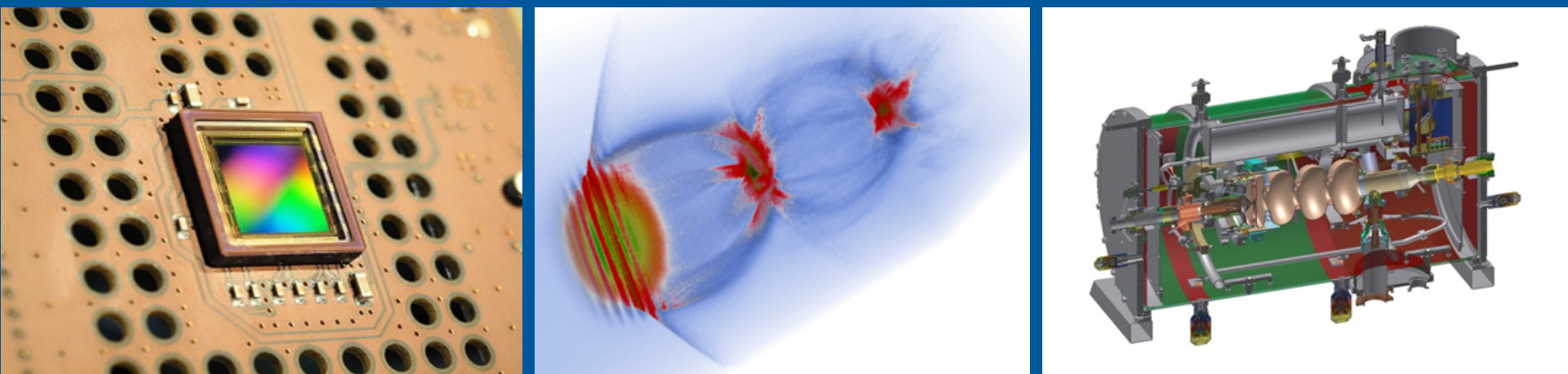
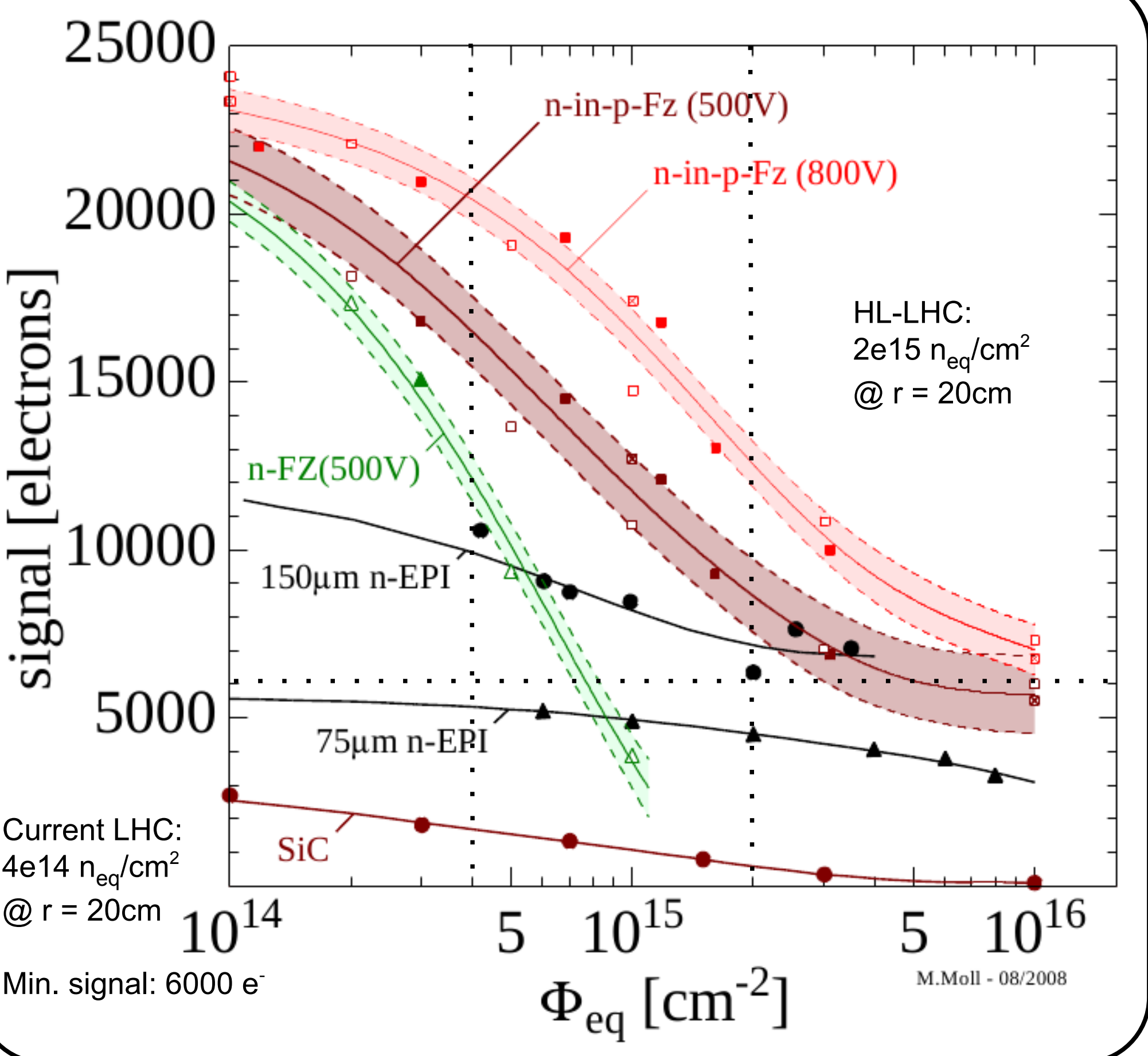


# Radiation-Hard Silicon Sensors for the High Luminosity LHC

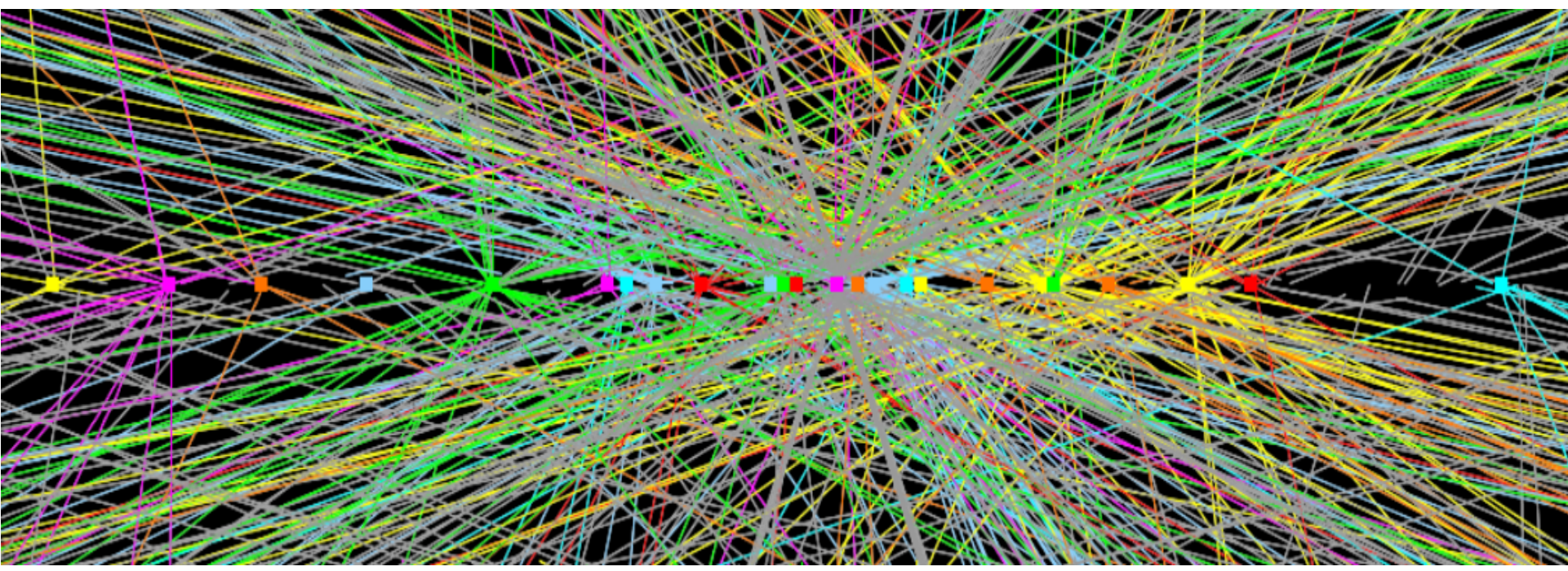


Thomas Eichhorn (DESY)

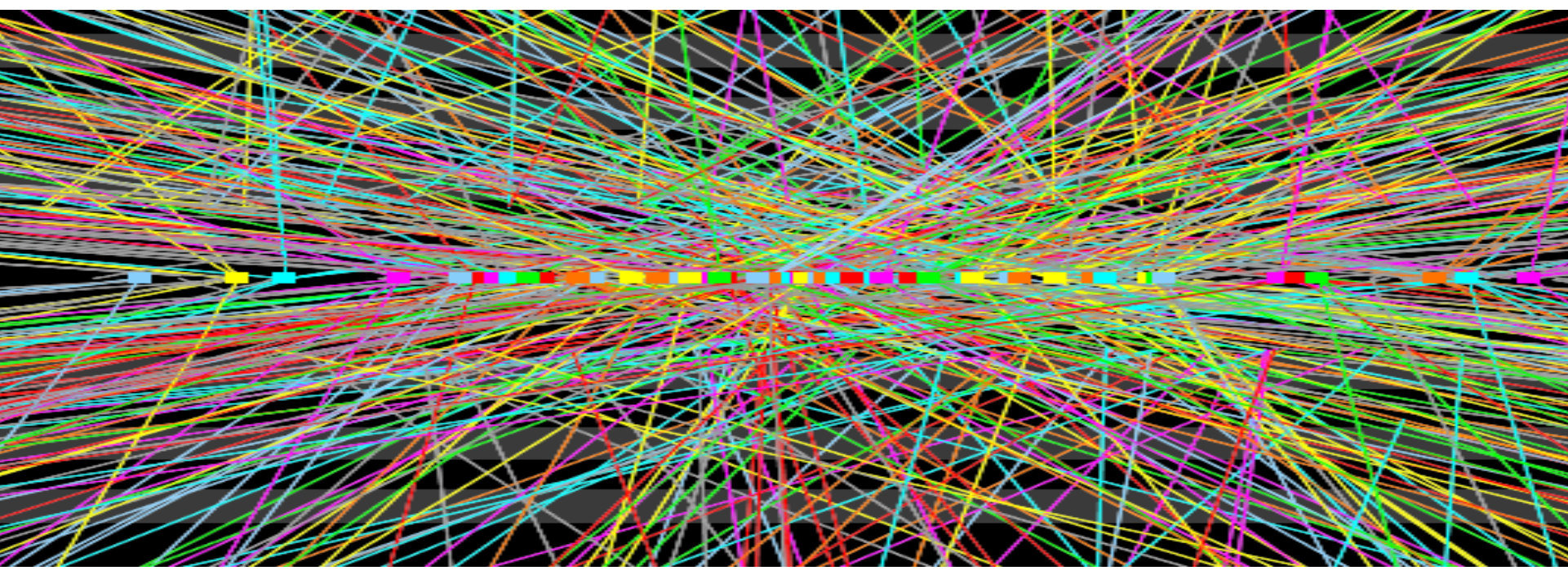


**High Luminosity-LHC from 2023:**  
→ Increase luminosity by a factor of 5  
→ Even harsher radiation environment

**Trackers for the HL-LHC experiment need upgrade to maintain current performance:**  
→ Improve granularity to keep low detector occupancy  
→ Develop radiation-hard sensors



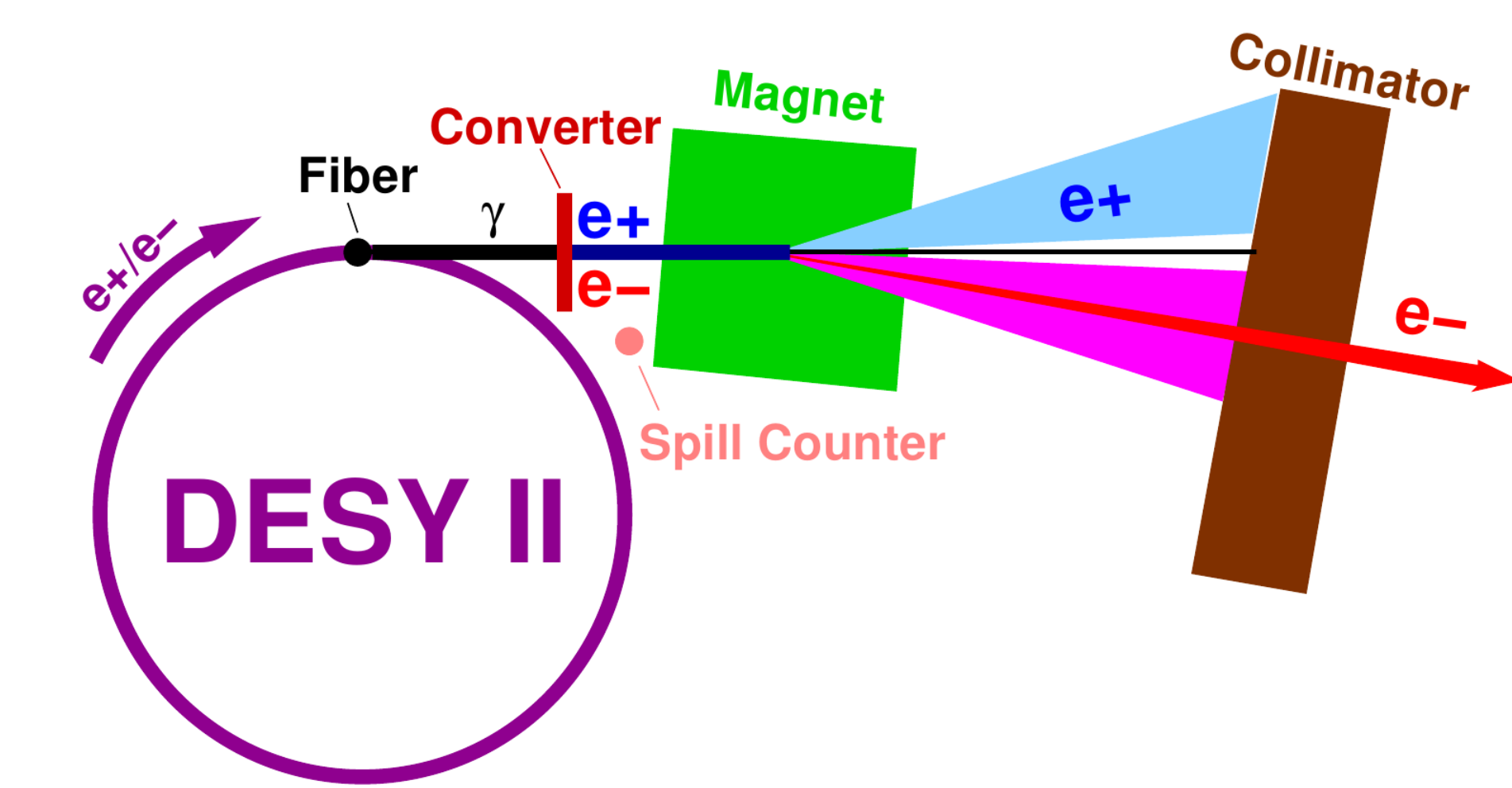
Pile-up collisions per event: Today: 40  
HL-LHC: 140



**Is epitaxially grown silicon a radiation-hard sensor material?**

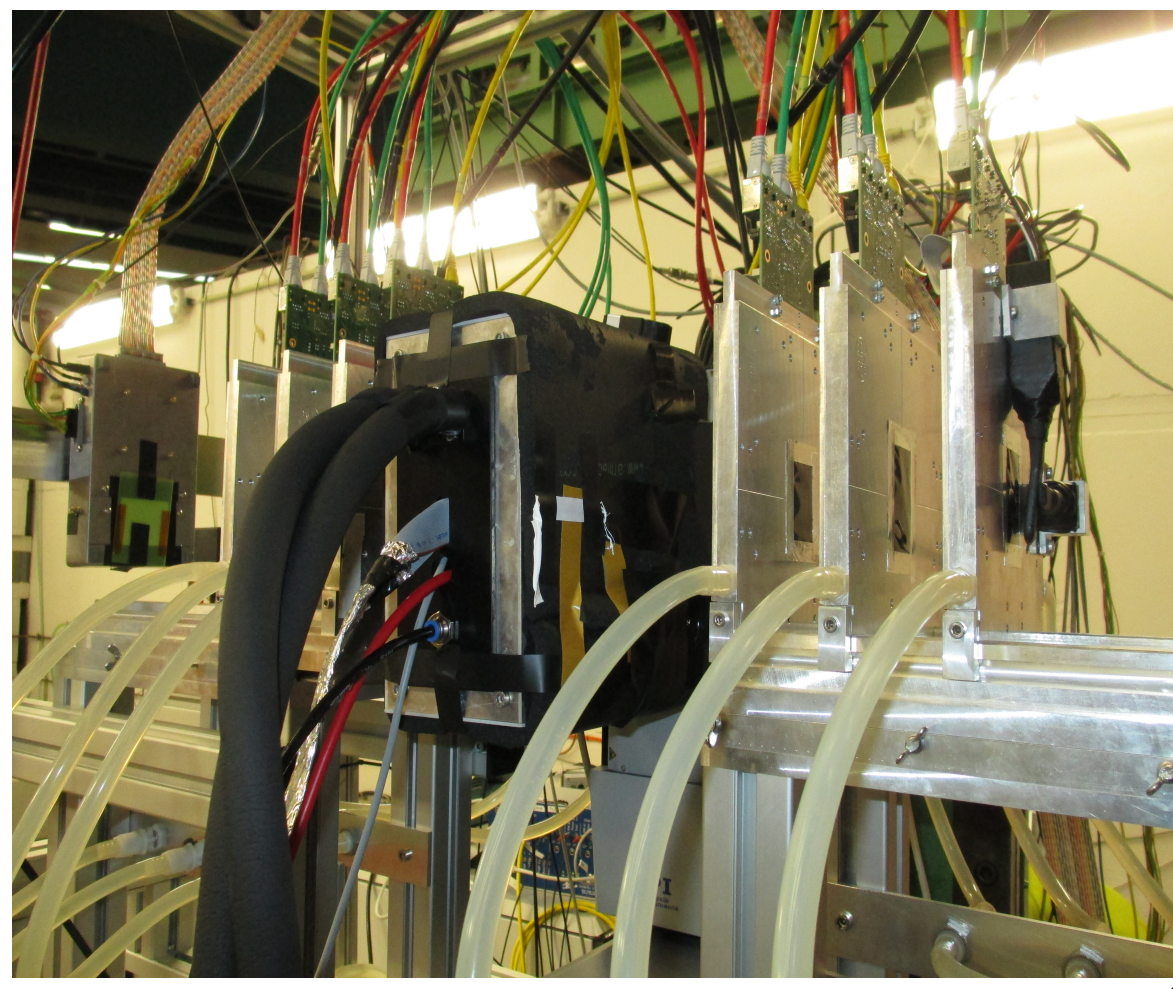
**Test beam measurements:**

Excellent DESY infrastructure available:  
→ 6 GeV e<sup>+</sup>/e<sup>-</sup> test beam facility



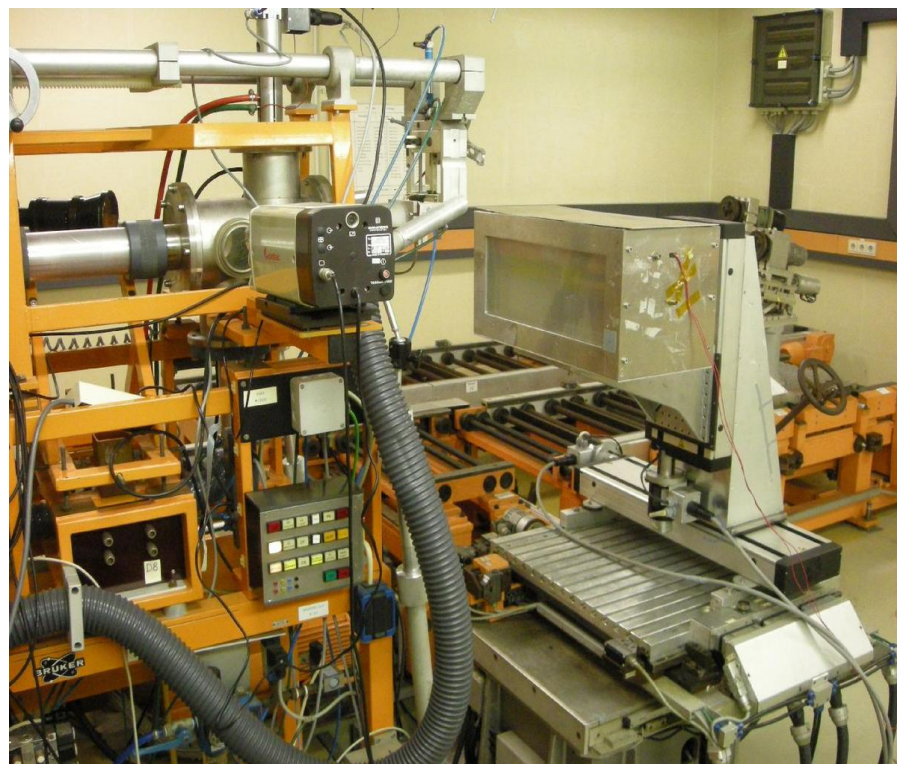
→ Pixel telescopes with μm tracking resolution:

evaluate and test sensor performance in the beam



**Investigate new technologies with different development tools:**  
→ Sensor irradiations  
→ Laboratory and test beam measurements with pixel telescopes  
→ TCAD simulations of test structures

**Karlsruhe Irradiation Center:**  
→ 25 MeV protons from Zyklotron AG

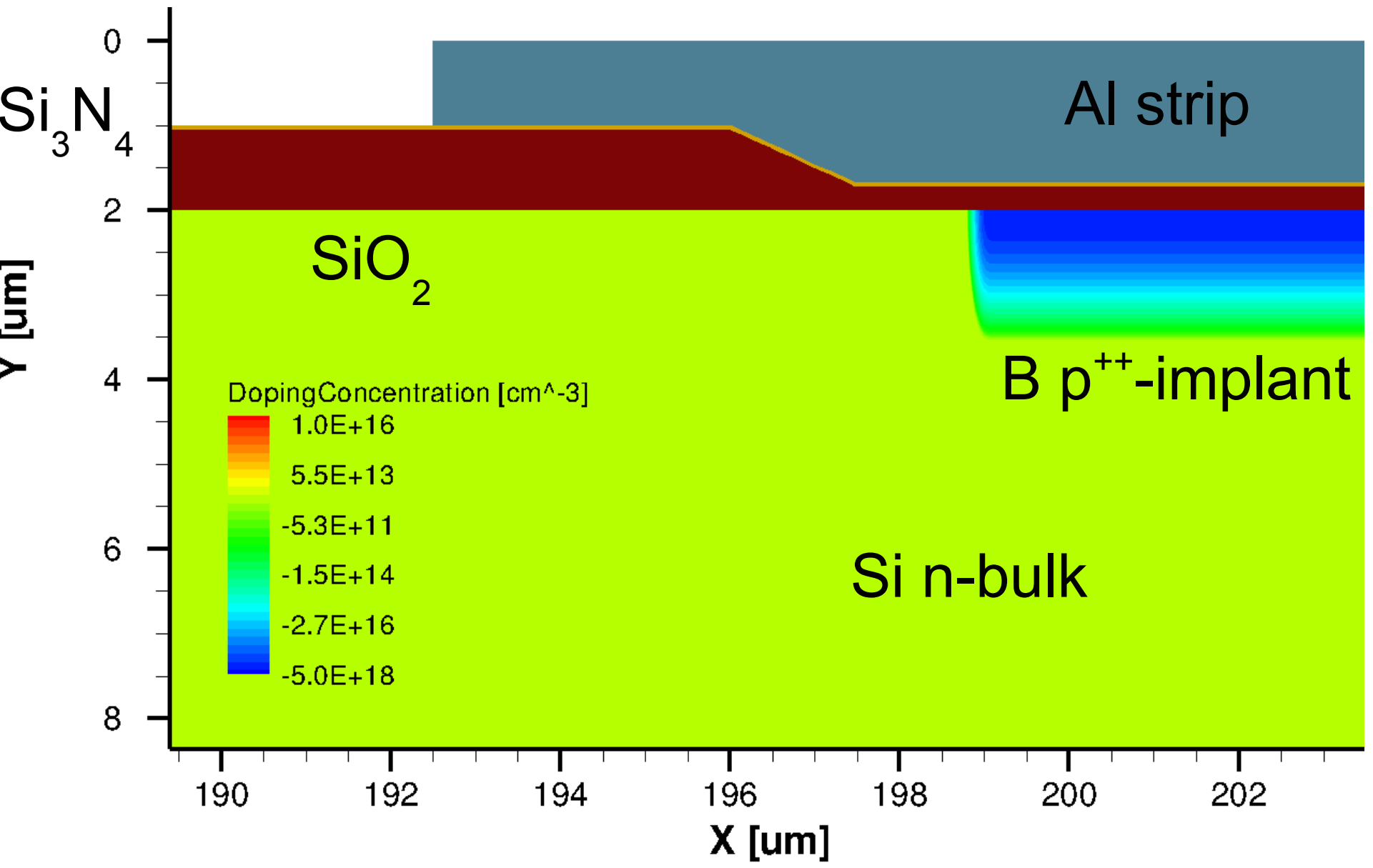


**Other irradiation centers:**  
→ CERN (23 GeV p)  
→ Los Alamos (800 MeV p)  
→ Ljubljana (1 MeV n)

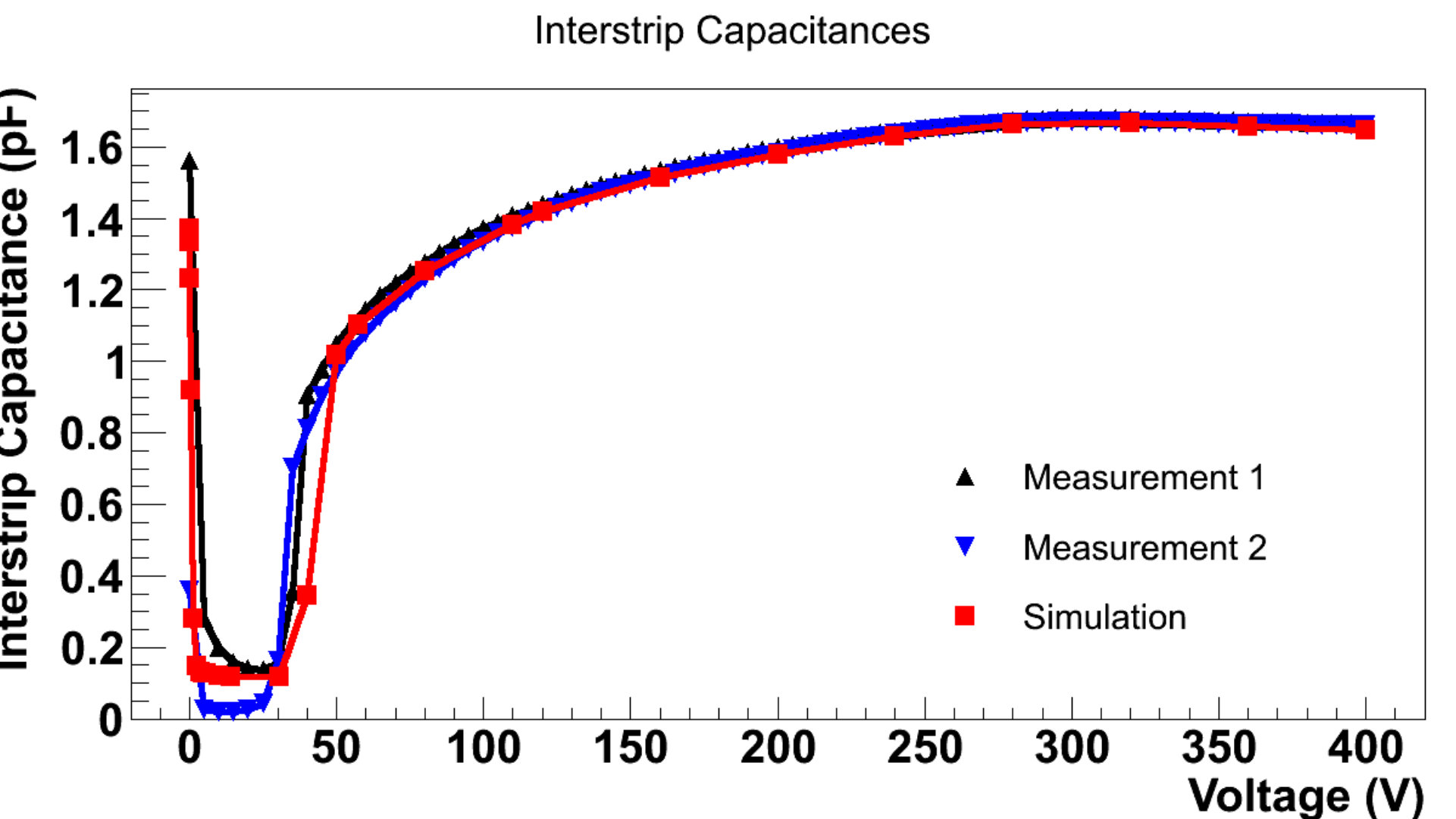
**Can the expected radiation damage effects in silicon be simulated?**

**TCAD Structure Simulations:**

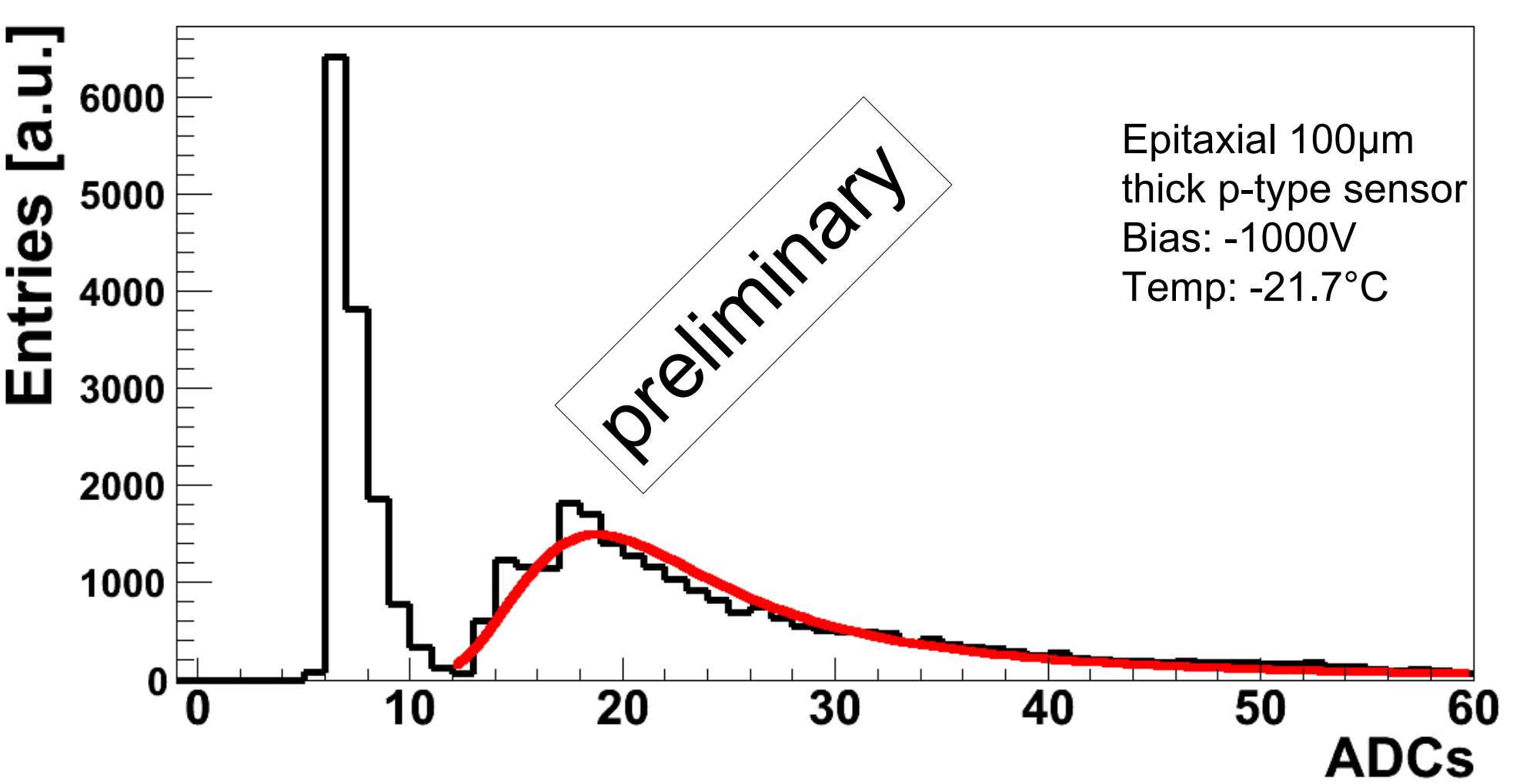
Reverse-engineer sensor structure



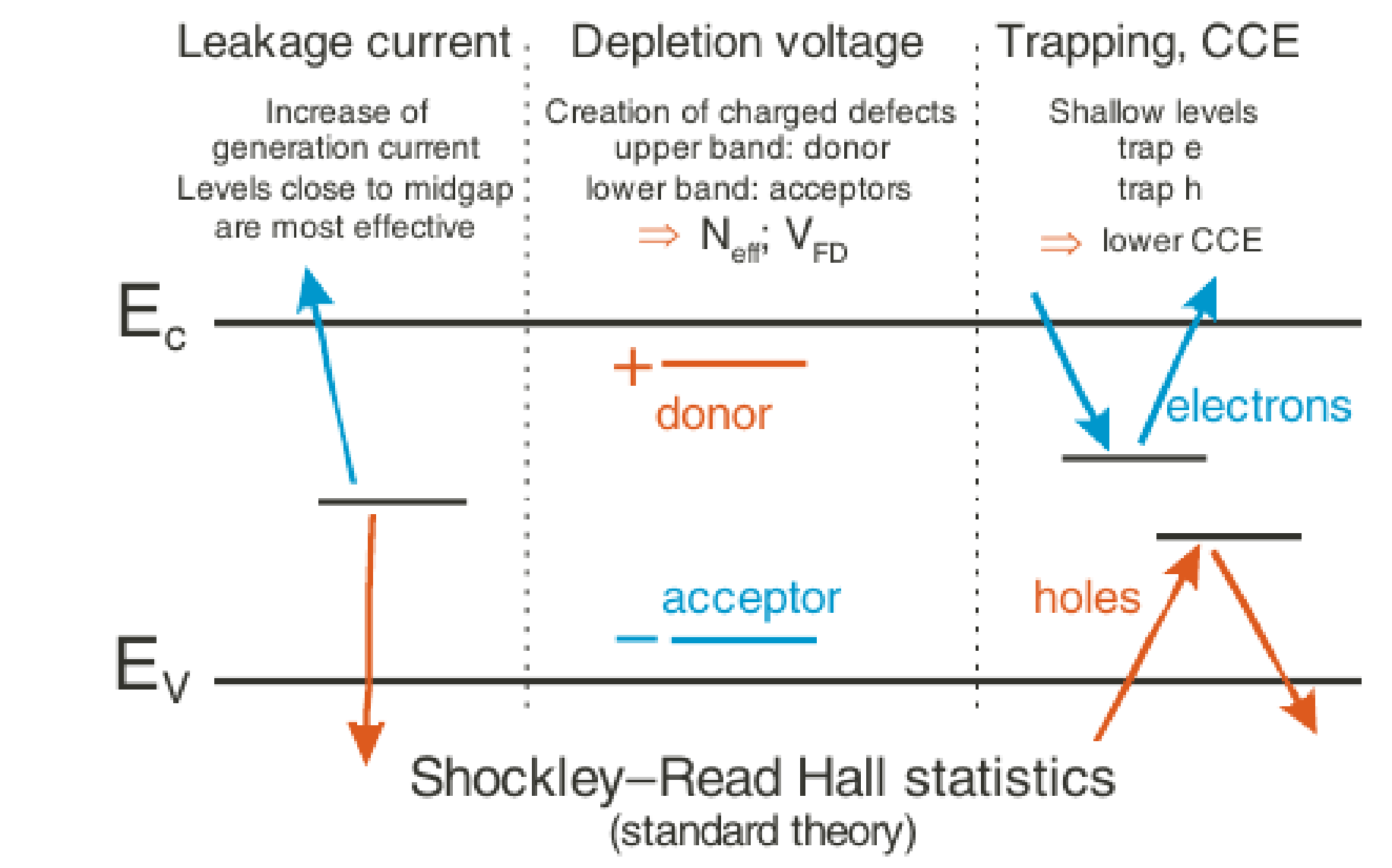
Comparison with lab measurements



**Testbeam campaign in 2013/2014:**  
→ Investigate epitaxial mini sensors from a run at a potential vendor  
→ Signal/noise levels after 3e15 neq/cm² proton irradiation:



**Bulk radiation damage:**  
→ acceptors and donors introduced



Model used implements one acceptor and one donor

**Surface radiation damage creates charges at the Si – SiO₂ interface, leading to spikes in the electric field**

